

SPECIFICATION

Device Name	:	IGBT Module
Type Name	:	7MBR25SA140-01
Spec. No.	:	MS6M 0550
Date	:	Jun. - 02 - 2000

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Matsumoto Factory

	DATE	NAME	APPROVED		Fuji Electric Co., Ltd.	
DRAWN	Jun. - 2 - '00	T. Kikuyasu			DWG. NO.	MS6M 0550
CHECKED	June - 2 - 00	D. Nishida				

Revised Records

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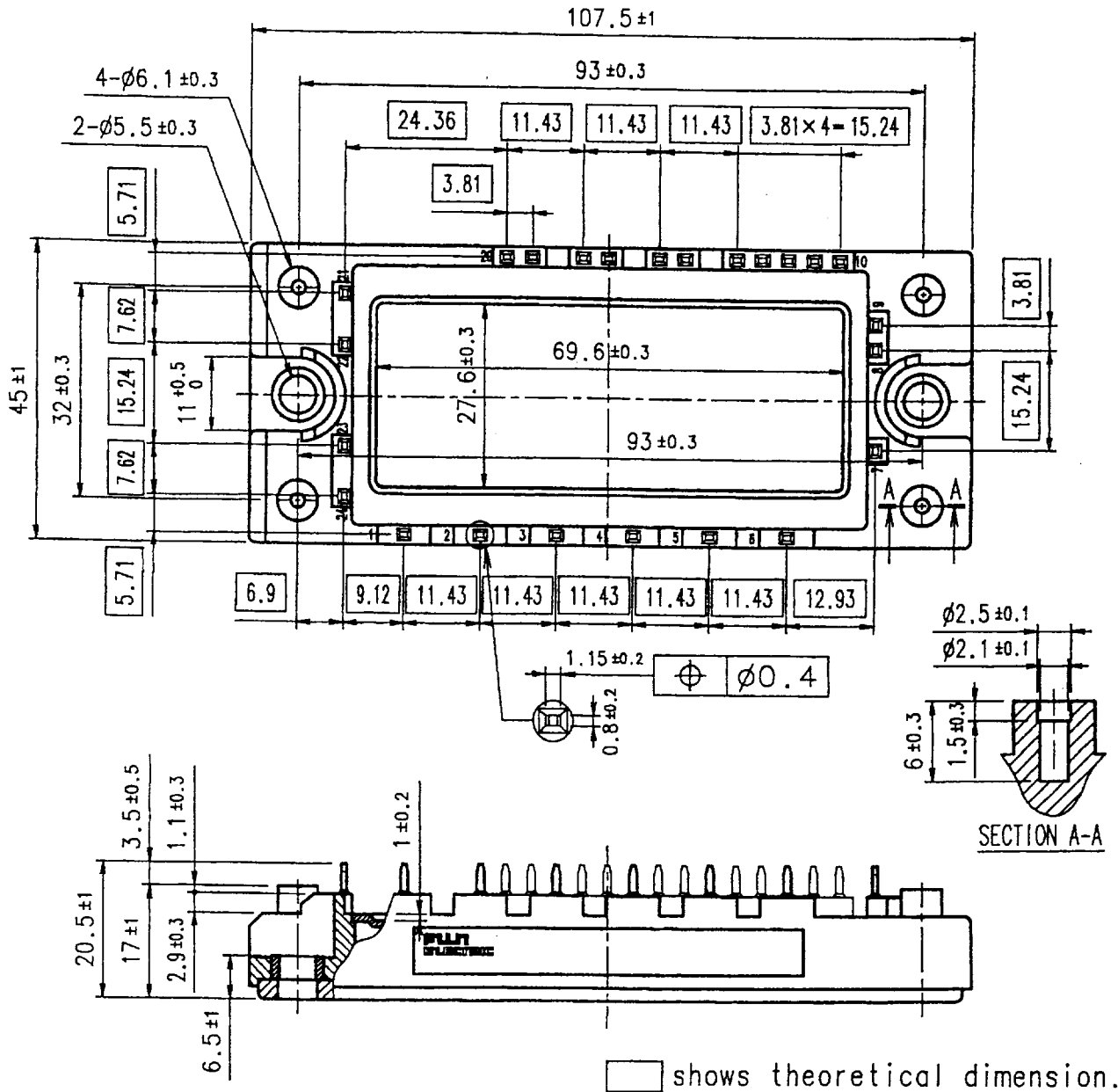
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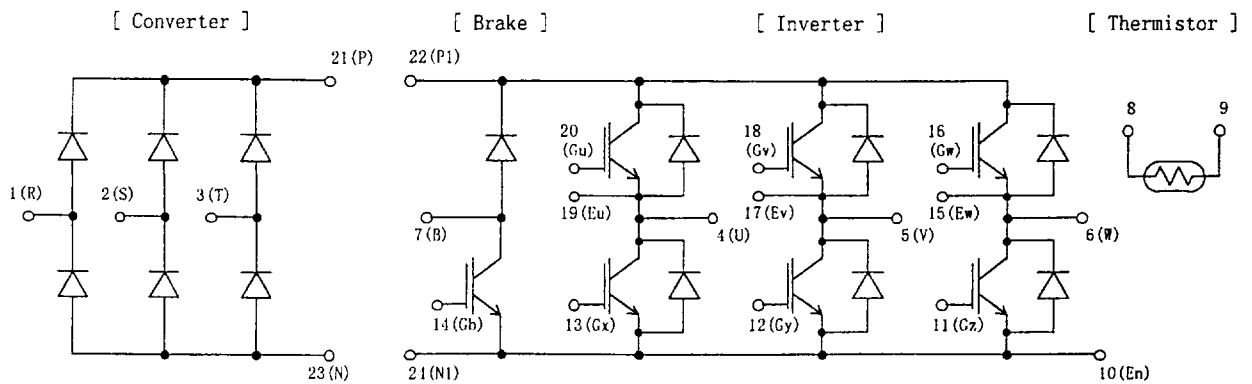
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7MBR25SA140-01

1. Outline Drawing (Unit : mm)



2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage	VCES			1400	V
	Gate-Emitter voltage	VGES			+20	V
	Collector current	Ic	Continuous	Tc=25C	35	A
				Tc=75C	25	
		Icp	1ms	Tc=25C	70	A
				Tc=75C	50	
	-Ic			25	A	
Collector Power Dissipation	Pc	1 device		180	W	
Brake	Collector-Emitter voltage	VCES			1400	V
	Gate-Emitter voltage	VGES			+20	V
	Collector current	Ic	Continuous	Tc=25C	25	A
				Tc=75C	15	
		Icp	1ms	Tc=25C	50	A
				Tc=75C	30	
	Collector Power Dissipation	Pc	1 device		110	W
Repetitive peak reverse Voltage(Diode)	VRRM			1400	V	
Converter	Repetitive peak reverse Voltage	VRRM			1600	V
	Average Output Current	Io	50Hz/60Hz sine wave		25	A
	Surge Current (Non-Repetitive)	IFSM	Tj=150C,10ms half sine wave		260	A
	I ² t (Non-Repetitive)	I ² t			338	A ² s
Junction temperature		Tj			150	C
Storage temperature		Tstg			-40~ +125	C
Isolation voltage	between terminal and copper base ^(*)	Viso	AC : 1min.		2500	V
	between thermistor and others ^(*)				2500	V
Mounting Screw Torque ^(*)					3.5	Nm

(*1) All terminals should be connected together when isolation test will be done.

(*2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*3) Recommendable Value : 2.5~3.5 Nm (M5)

4. Electrical characteristics (at Tj= 25C unless otherwise specified)

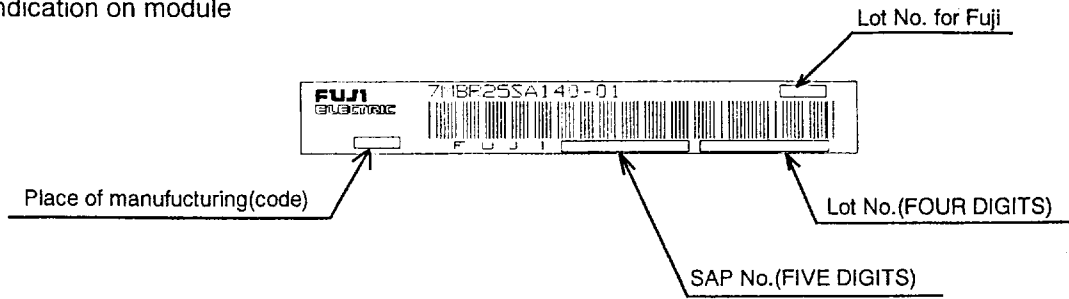
Items		Symbols	Conditions	Characteristics			Units
				min.	typ.	Max.	
Inverter	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE = 1400 V			1.0	mA
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = +20 V			200	nA
	Gate-Emitter threshold voltage	VGE(th)	VCE = 20 V, Ic = 25 mA	5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip		2.2		V
			Ic = 25 A terminal		2.3	2.7	
	Input capacitance	Cies	VGE = 0 V, VCE = 10 V f = 1 MHz		3000		pF
	Turn-on time	ton	Vcc = 800 V		0.35	1.2	us
		tr	Ic = 25 A		0.25	0.6	
		tr(0)	VGE = +-15 V		0.1		
	Turn-off time	toff	RG = 51 ohm		0.45	1.0	
		tf			0.08	0.3	
	Forward on voltage	VF	IF = 25 A chip		2.4		V
			terminal		2.5	3.3	
	Reverse recovery time	trr	IF = 25 A			350	ns
Brake	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE = 1400 V			1.0	mA
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = +-20 V			200	nA
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip		2.2		V
			Ic = 15 A terminal		2.3	2.7	
	Turn-on time	ton	Vcc = 800 V		0.35	1.2	us
		tr	Ic = 15 A		0.25	0.6	
	Turn-off time	toff	VGE = +-15 V		0.45	1.0	
		tf	RG = 82 ohm		0.08	0.3	
	Reverse current	IRRM	VR = 1400 V			1.0	mA
Converter	Forward on voltage	VFM	IF = 25 A chip		1.1		V
			terminal		1.2	1.5	
	Reverse current	IRRM	VR = 1600 V			1.0	mA
Thermistor	Resistance	R	T = 25C		5000		ohm
			T = 100C	465	495	520	
	B value	B	T = 25/50C	3305	3375	3450	K

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			0.69	C/W
		Inverter FWD			1.30	
		Brake IGBT			1.14	
		Converter Diode			0.90	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module



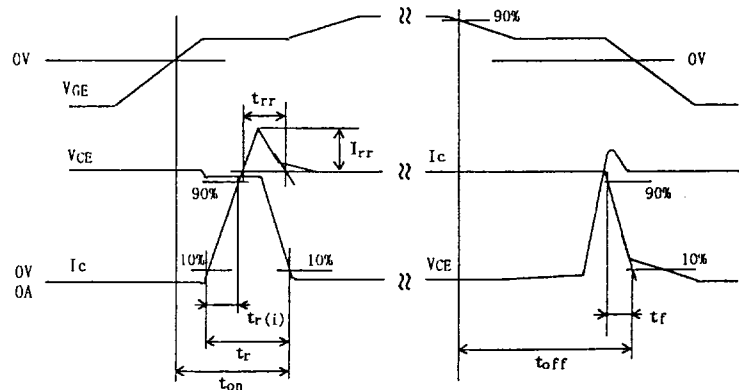
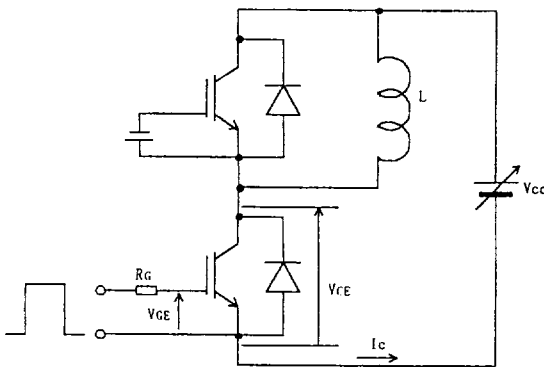
7. Applicable category

This specification is applied to Power Integrated Module named 7MBR25SA140-01 .

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

9. Definitions of switching time



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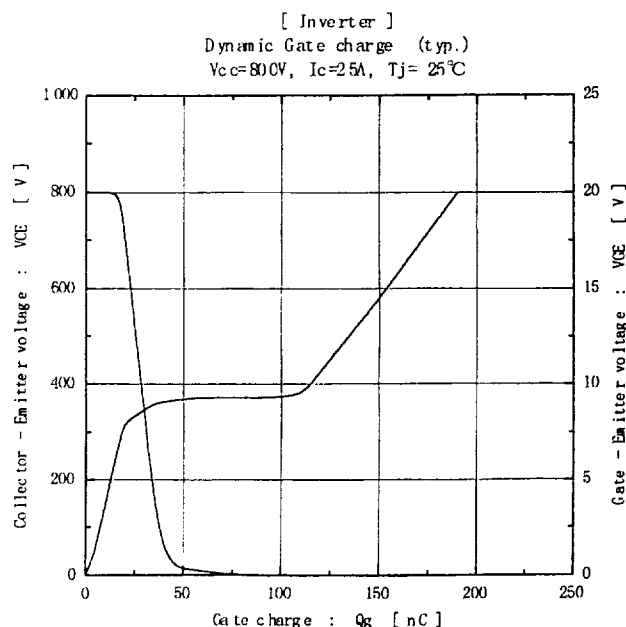
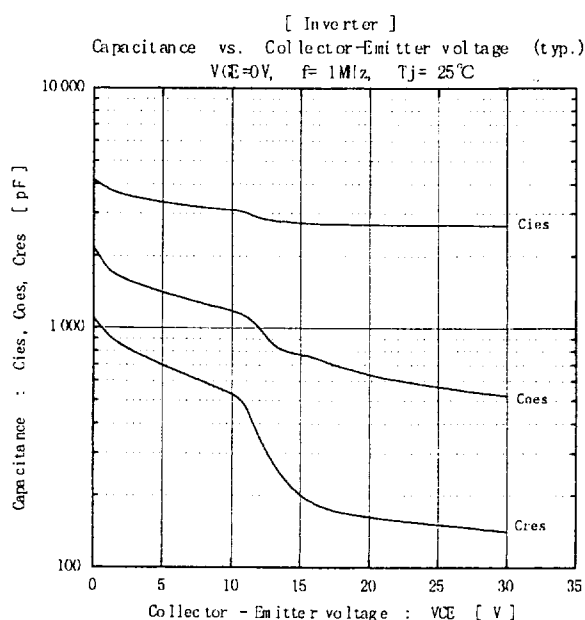
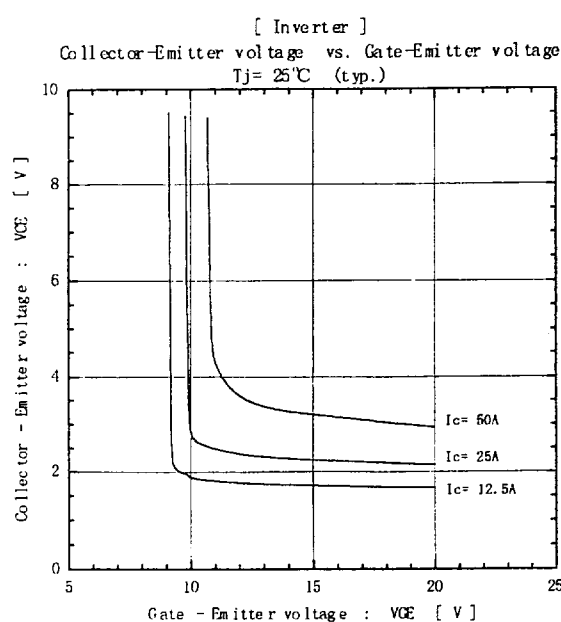
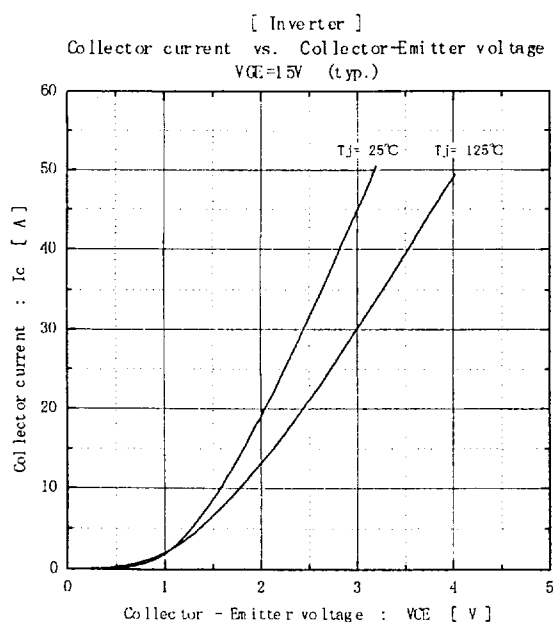
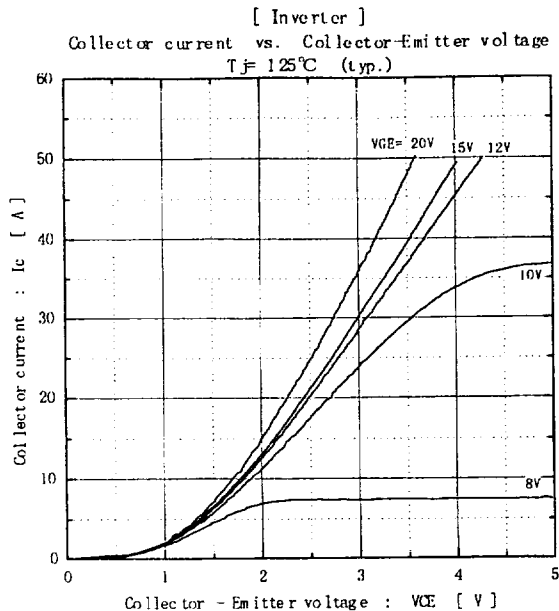
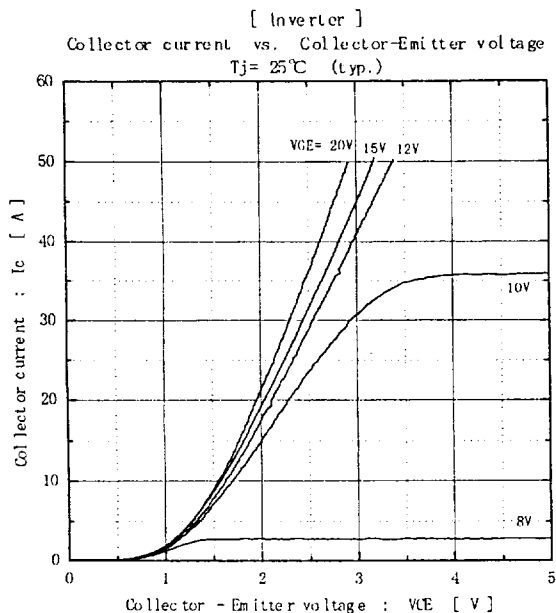
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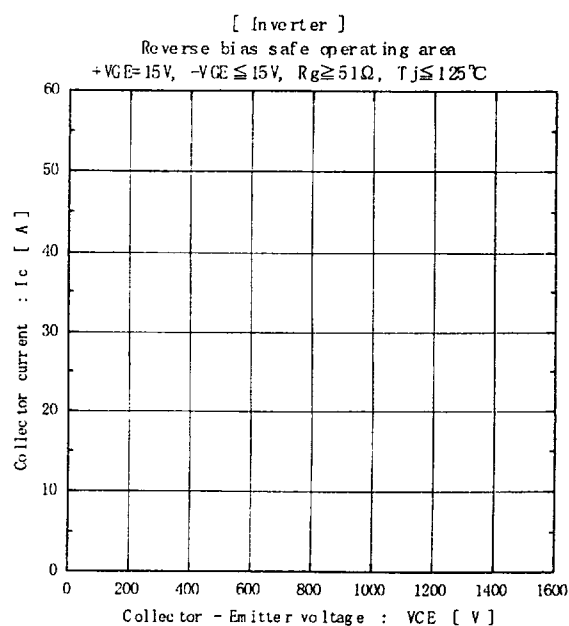
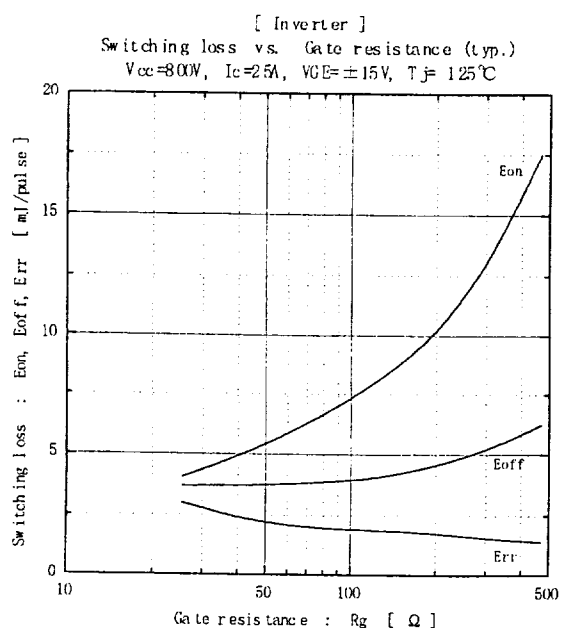
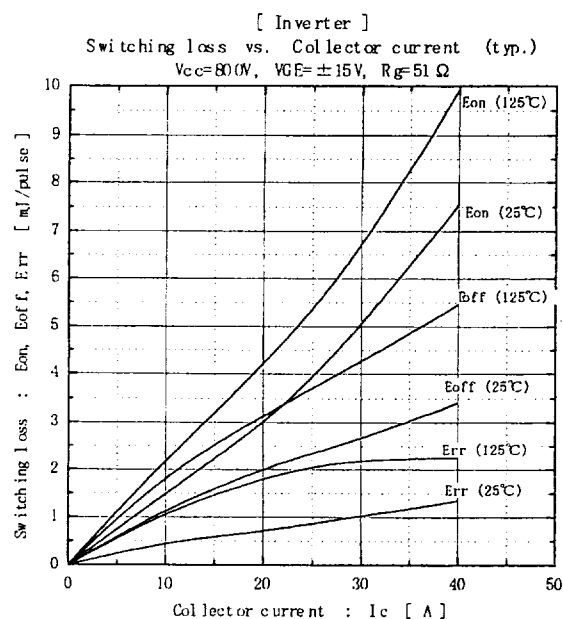
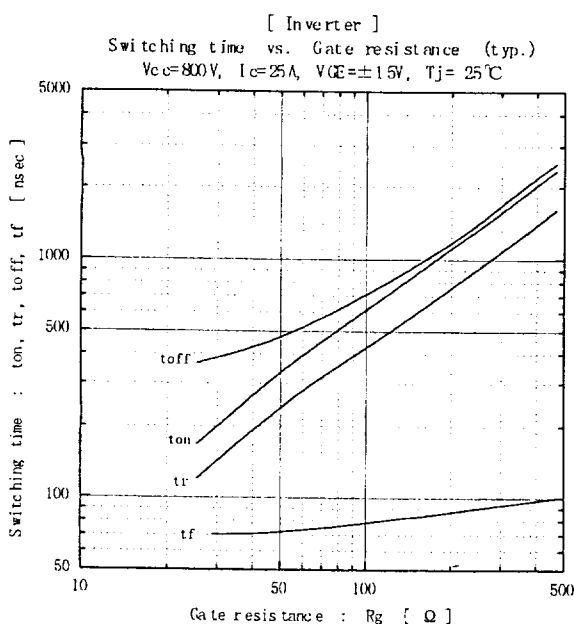
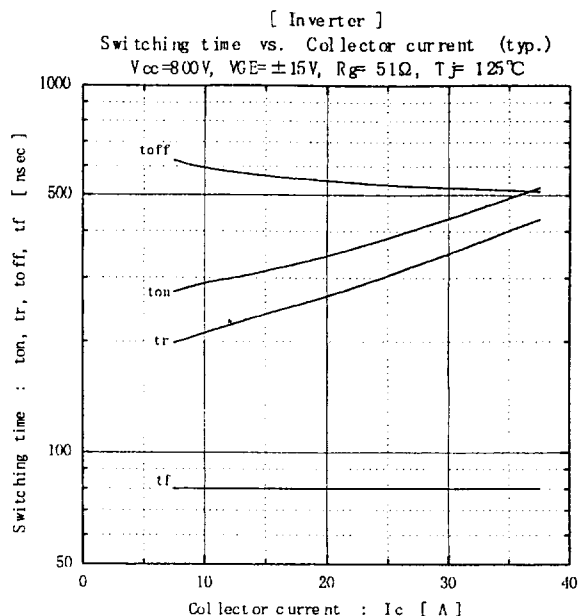
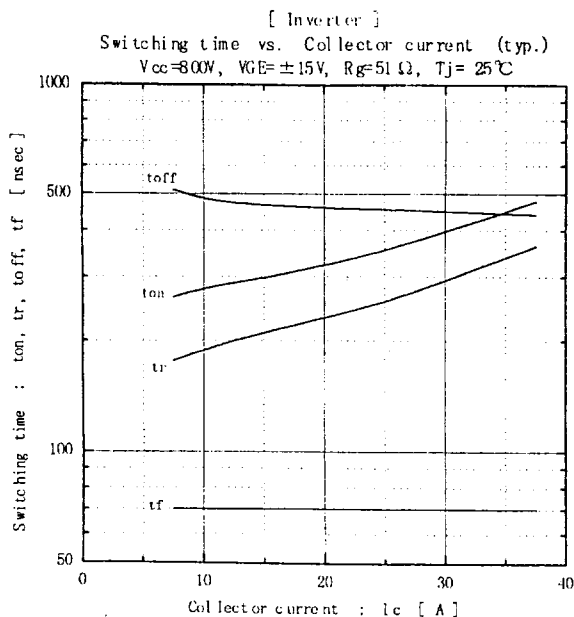
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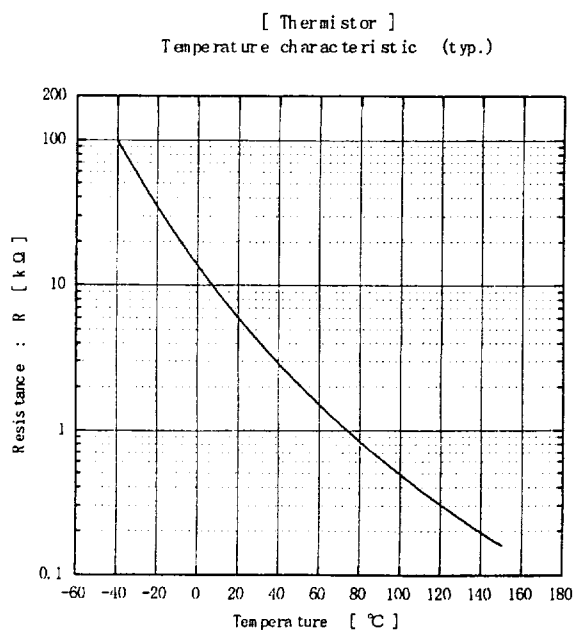
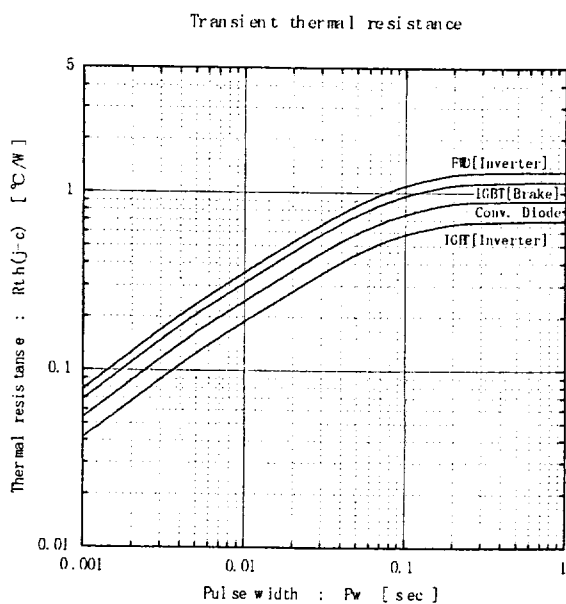
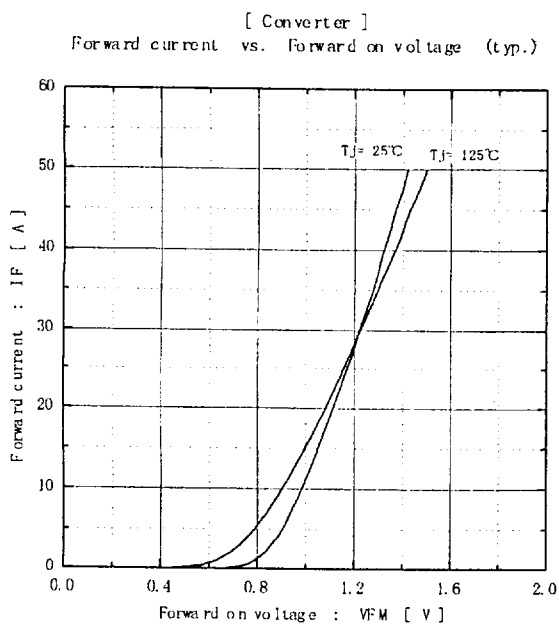
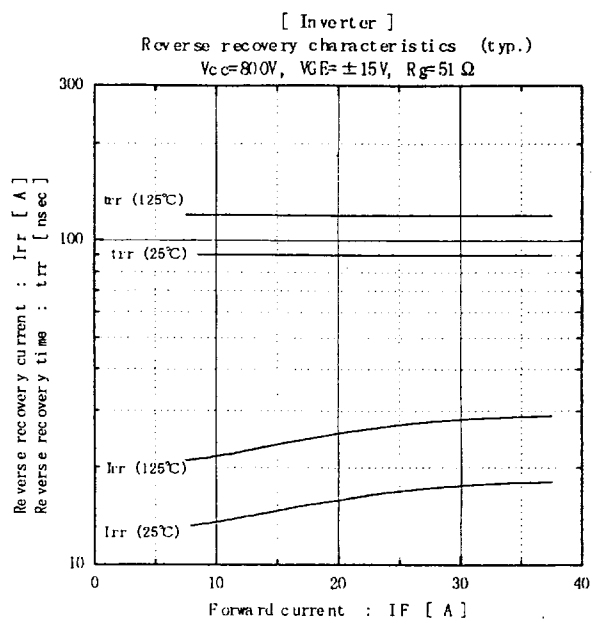
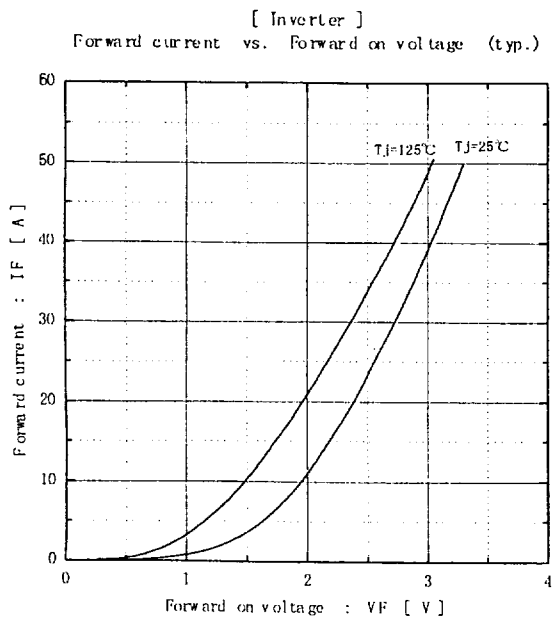
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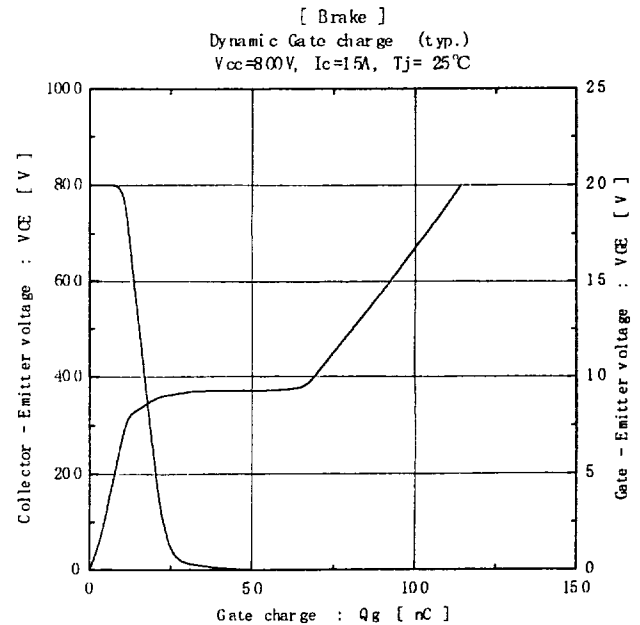
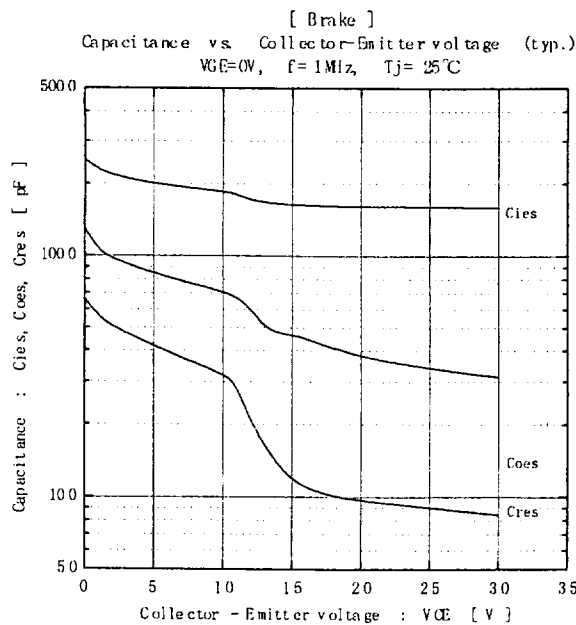
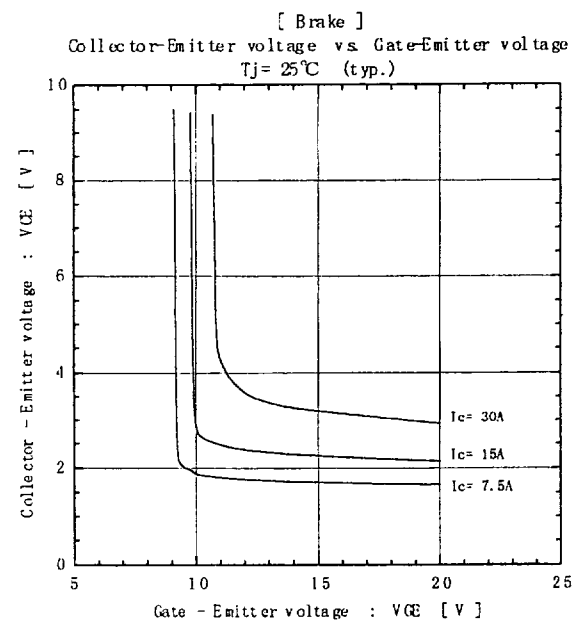
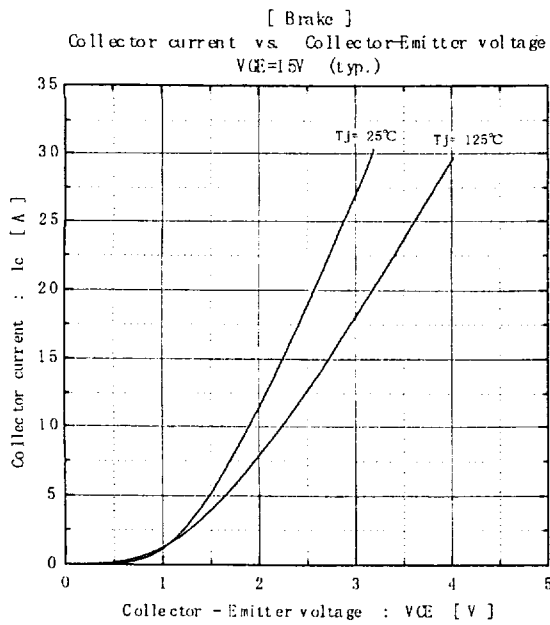
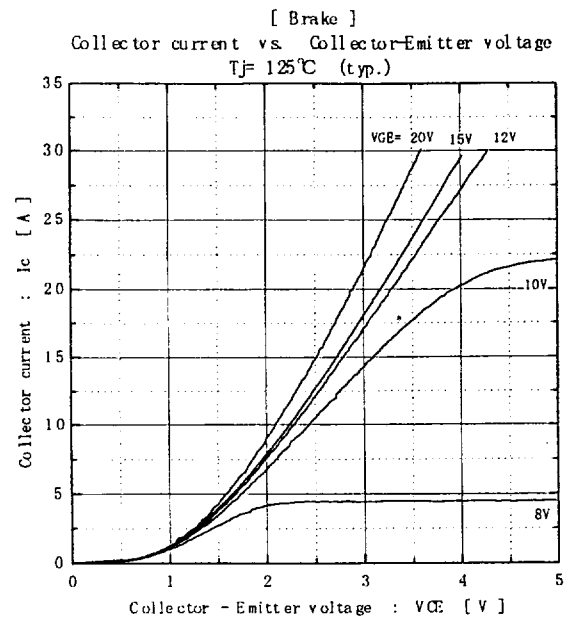
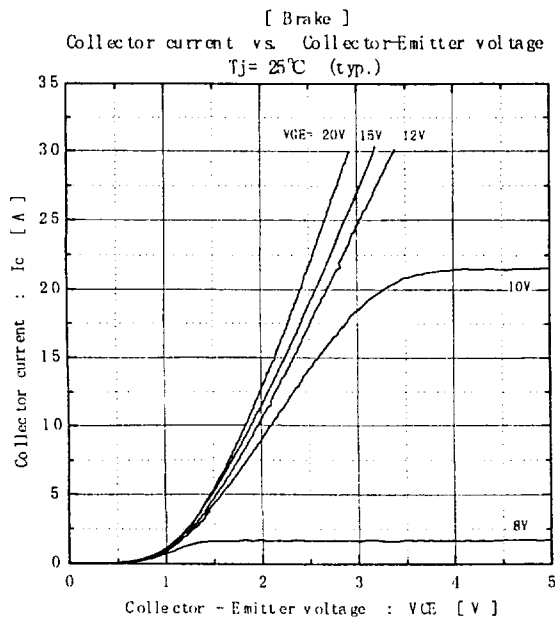
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